

Supplementary Materials

# Hole Doping to Enhance the Photocatalytic Activity of $\text{Bi}_4\text{NbO}_8\text{Cl}$

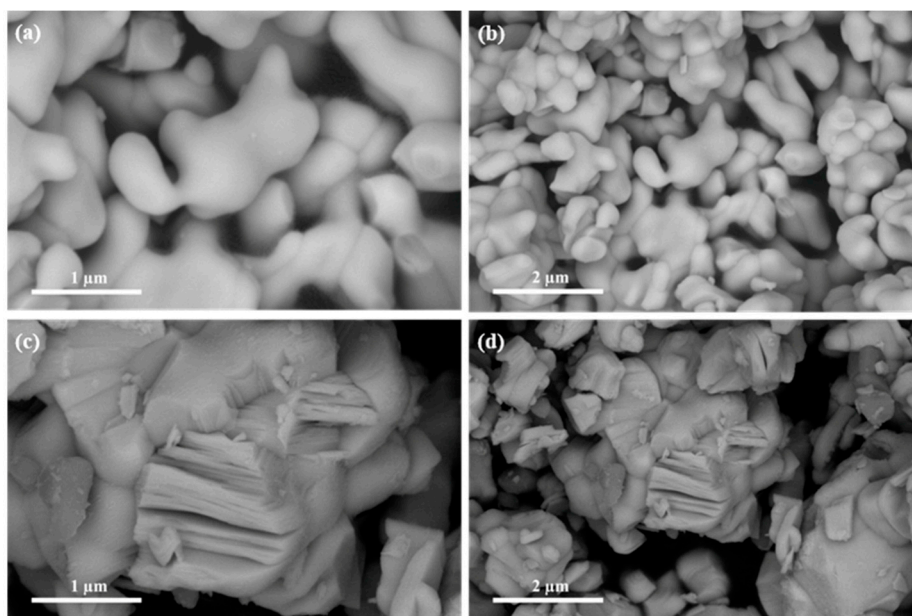
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**Figure S1.** SEM images of  $\text{Bi}_4\text{Nb}_{0.9}\text{Zn}_{0.1}\text{O}_8\text{Cl}$  (a) (b);  $\text{Bi}_4\text{Nb}_{0.7}\text{Zn}_{0.3}\text{O}_8\text{Cl}$  (c) (d).